

## isc N-Channel MOSFET Transistor

# IPW50R350CP

#### • FEATURES

- Static drain-source on-resistance: R<sub>DS</sub>(on)≤350mΩ
- Enhancement mode:
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION



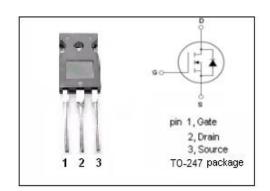
High Peak Current Capability

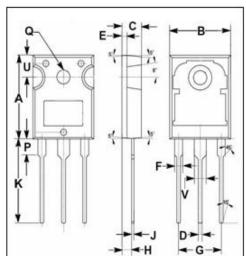
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
$V_{\text{DSS}}$	Drain-Source Voltage	500	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	10	А
I <sub>DM</sub>	Drain Current-Single Pulsed	22	А
P <sub>D</sub>	Total Dissipation @Tc=25°C	89	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}$ C
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$ C

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	1.4	°C/W
Rth(j-a)	Channel-to-ambient thermal resistance	62	°C/W





8 - 3	mm			
DIM	MIN	MAX		
Α	19.80	20.20		
В	15.40	15.80		
C	4.90	5.10		
D	0.90	1.10		
E	1.40	1.60		
F	1.90	2.10		
G	10.80	11.00		
Н	2.40	2.60		
J	0.50	0.70		
K	19.50	20.50		
P	3.90	4.10		
Q	3.30	3.50		
U	5.20	5.40		
V	2.90	3.10		



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25°C unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =250 μ A	500			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	VDS=VGS; I <sub>D</sub> =440 μ A	2.5		3.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =5.6A			0.35	Ω
l <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = 20V; V <sub>DS</sub> = 0V			0.1	μ <b>А</b>
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =500V; V <sub>GS</sub> = 0V			1	μ <b>А</b>
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> =5.6A, V <sub>GS</sub> = 0V			1.2	V

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